

1SS400T1G

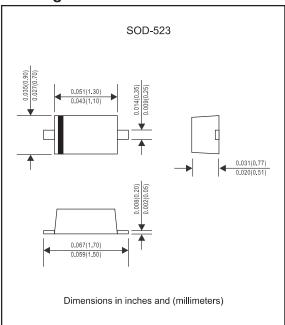
High Speed Switching Diode



FEATURES

- Small surface mounting type
- High speed
- High reliability with high surge current handing capability

Package outline



Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25℃

Parameter	Symbol	Limit	Unit
Non-Repetitive Peak Reverse Voltage	V_{RM}	90	V
DC Blocking Voltage	V_{R}	80	V
Forward Continuous Current	I _{FM}	225	mA
Average Rectified Output Current	Io	100	mA
Non-Repetitive Peak Forward Surge Current @t=8.3ms	I _{FSM}	2.0	А
Power Dissipation	Pd	150	mW
Thermal Resistance Junction to Ambient	$R_{ heta JA}$	833	°C/W
Operation Junction and Storage Temperature Range	T_J, T_{STG}	-55~+150	$^{\circ}$

Electrical Ratings @Ta=25℃

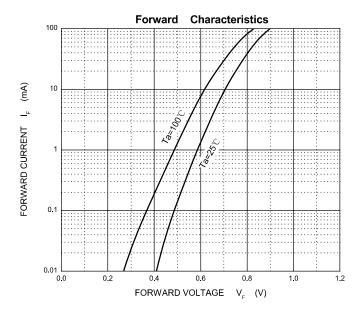
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	V _F			1.2	V	I _F =100mA
Reverse current	I _R			0.1	μA	V _R =80V
Capacitance between terminals	Ст			3.0	pF	V _R =0.5V, f=1MHz
Reverse recovery time	t _{rr}			4	ns	$V_R=6V,I_F=10mA,R_L=100\Omega$

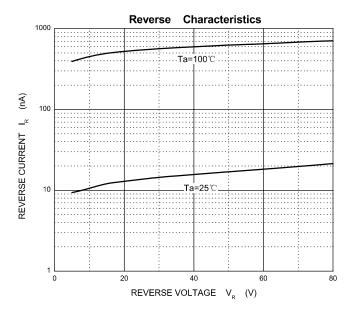


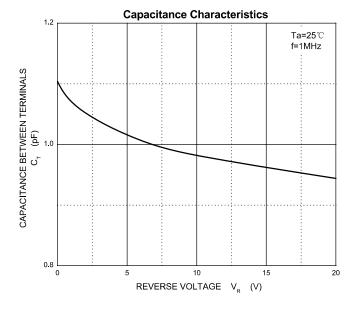
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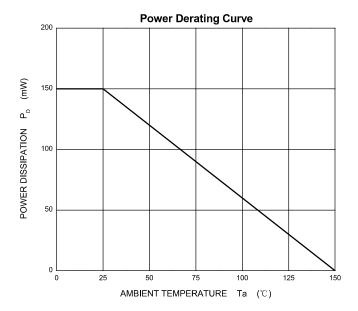
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Typical Characteristics









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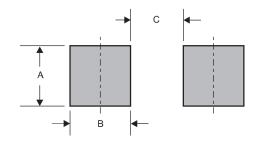
Pinning information

Pin	Simplified outline	Symbol
Pin1 cathode Pin2 anode	1 🗔 🗆 2	1 2

Marking

Type number	Marking code
1SS400T1G	Α

Suggested solder pad layout



Dimensions in inches and (millimeters)

PACKAGE	Α	В	С
SOD-523	0.032 (0.80)	0.024 (0.60)	0.044 (1.10)